RENESAS

HD74AC123A

Dual Retriggerable Resettable Multivibrator

REJ03D0245–0200Z (Previous ADE-205-365 (Z)) Rev.2.00 Jul.16.2004

Description

Each half of the HD74AC123A features retriggerable capability, complementary dc level triggering and overriding Direct Clear. When a circuit is in the quasi-stable (delay) state, another trigger applied to the inputs (per the Truth Table) will cause the delay period to start again, without disturbing the outputs. By repeating this process, the output pulse period (Q High, \overline{Q} Low) can be made as long as desired. Alternatively, a delay period can be terminated at any time by a Low signal on \overline{C}_D , which also inhibits triggering. An internal connection from \overline{C}_D to the input gate makes it possible to trigger the circuit by a positive-going signal on \overline{C}_D , as shown in the Truth Table. For timing capacitor values greater than 1000 pF, the output pulse width is defined as follows.

Where t_w is in ns, R_X is in $k\Omega$ and C_X is in pF. $t_w = R_X C_X$

Features

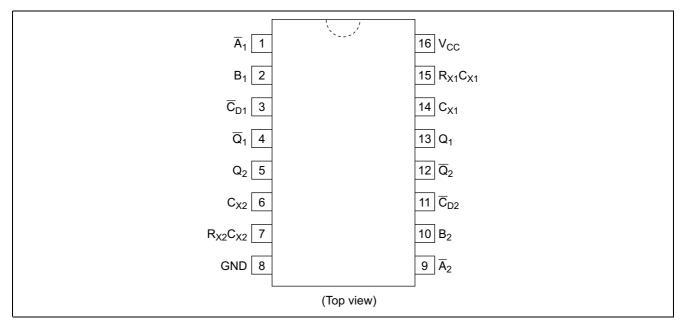
- Outputs Source/Sink 24 mA
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74AC123AP	DIP-16 pin	DP-16E, -16FV	Р	
HD74AC123AFPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74AC123ARPEL	SOP-16 pin (JEDEC)	FP-16DNV	RP	EL (2,500 pcs/reel)

Notes: 1. Please consult the sales office for the above package availability.

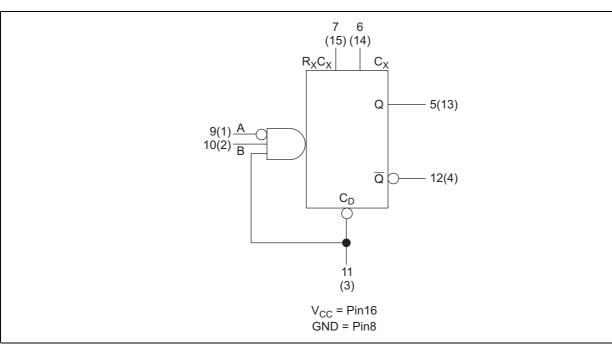
2. The packages with lead-free pins are distinguished from the conventional products by adding V at the end of the package code.

Pin Arrangement





Logic Symbol



Pin Names

$\overline{A}_1, \overline{A}_2$	Trigger Inputs (Active Falling Edge)
B ₁ , B ₂	Trigger Inputs (Active Rising Edge)
$\overline{C}_{D1}, \overline{C}_{D2}$	Direct Clear Inputs (Active Low)
Q_1, Q_2	Positive Pulse Outputs
$\overline{\mathbf{Q}}_1, \overline{\mathbf{Q}}_2$	Negative Pulse Outputs

Triggering Truth Table

Inputs			
A	В	$\overline{\mathbf{C}}_{D}$	Response
x	Х	L	No trigger
<u> </u>	L	х	No trigger
<u> </u>	Н	Н	Trigger
Н		х	No trigger
L		Н	Trigger
L	Н		Trigger

H : High Voltage Level

L : Low Voltage Level

X : Immaterial

___: Low-to-High Transition

L: High-to-Low Transition



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V _{cc}	–0.5 to 7	V	
DC input diode current	I _{IK}	-20	mA	$V_1 = -0.5V$
		20	mA	$V_1 = Vcc+0.5V$
DC input voltage	V	-0.5 to Vcc+0.5	V	
DC output diode current	Ι _{οκ}	-50	mA	V _o = -0.5V
		50	mA	$V_{o} = Vcc+0.5V$
DC output voltage	Vo	-0.5 to Vcc+0.5	V	
DC output source or sink current	I _o	±50	mA	
DC V_{cc} or ground current per output pin	I _{CC} , I _{GND}	±50	mA	
Storage temperature	Tstg	–65 to +150	°C	

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V _{cc}	2 to 6	V	
Input and output voltage	V _I , V _O	0 to V _{cc}	V	
Operating temperature	Та	-40 to +85	°C	
Input rise and fall time	tr, tf	8	ns/V	V _{CC} = 3.0V
(except Schmitt inputs)				V _{cc} = 4.5 V
V_{IN} 30% to 70% V_{CC}				V _{cc} = 5.5 V

DC Characteristics

ltem	Sym- bol	Vcc (V)	1	Га = 25°(C	Ta = –40 to +85°C		Unit	Condition
			min.	typ.	max.	min.	max.		
Input Voltage	V _{IH}	3.0	2.1	1.5	—	2.1	—	V	V_{OUT} = 0.1 V or V_{CC} –0.1 V
		4.5	3.15	2.25	—	3.15	_		
		5.5	3.85	2.75	—	3.85	_		
	V _{IL}	3.0	—	1.50	0.9	—	0.9		V_{OUT} = 0.1 V or V_{CC} –0.1 V
		4.5	—	2.25	1.35	_	1.35		
		5.5	—	2.75	1.65	_	1.65		
Output voltage	V _{OH}	3.0	2.9	2.99	_	2.9	_	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$
		4.5	4.4	4.49	—	4.4	_		I _{OUT} = -50 μA
		5.5	5.4	5.49	—	5.4	—		
		3.0	2.58	_	—	2.48	—		$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -12 \text{ mA}$
		4.5	3.94	—	—	3.80	_		I _{он} = –24 mA
		5.5	4.94	—	—	4.80	_		I _{он} = –24 mA
	V _{OL}	3.0	—	0.002	0.1	_	0.1		$V_{IN} = V_{IL} \text{ or } V_{IH}$
		4.5	—	0.001	0.1	_	0.1		I _{OUT} = 50 μA
		5.5	—	0.001	0.1	_	0.1		
		3.0	—	—	0.32	_	0.37		$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OL} = 12 \text{ mA}$
		4.5	—	—	0.32	_	0.37		I _{OL} = 24 mA
		5.5	—	—	0.32	_	0.37		I _{OL} = 24 mA
Input leakage current	I _{IN}	5.5	-	—	±0.1	-	±1.0	μA	$V_{IN} = V_{CC}$ or GND
Dynamic output	I _{OLD}	5.5	—		—	86	_	mA	V _{OLD} = 1.1 V
current*	I _{OHD}	5.5	—		—	-75	_	mA	V _{OHD} = 3.85 V
Quiescent supply current	I _{cc}	5.5	—	—	130	—	220	μA	$V_{IN} = V_{CC}$ or ground

*Maximum test duration 2.0 ms, one output loaded at a time.



AC Characteristics: HD74AC123A

			Ta = +25°C C _∟ = 50 pF		Ta = -40°C to +85°C C _L = 50 pF				
ltem	Symbol	V _{cc} (V)* ¹	Min	Тур	Max	Min	Max	Unit	Condition
Propagation delay	t _{PLH}	3.3	1.0	—	19.0	1.0	22.0	ns	Cext = 0 pF
Ā or B to Q		5.0	1.0	—	15.0	1.0	17.0		Rest = 5 kΩ
Propagation delay	t _{PHL}	3.3	1.0	—	19.0	1.0	22.0	ns	
\overline{A} or B to \overline{Q}		5.0	1.0	—	15.0	1.0	17.0		
Propagation delay	t _{PLH}	3.3	1.0	—	15.0	1.0	18.0	ns	
\overline{C}_{Dn} to \overline{Q}		5.0	1.0	—	12.0	1.0	13.5		
Propagation delay	t _{PHL}	3.3	1.0	—	15.0	1.0	18.0	ns	
\overline{C}_{Dn} to Q		5.0	1.0		12.0	1.0	13.5		

Note: 1. Voltage Range 3.3 is $3.3 \text{ V} \pm 0.3 \text{ V}$

Voltage Range 5.0 is 5.0 V \pm 0.5 V

AC Operating Requirements: HD74AC123A

			Ta = +25°C C _∟ = 50 pF		Ta = -40 to +85°C C _L = 50 pF		
Item	Symbol	V _{cc} (V)* ¹	Тур	Guarantee	d Minimum	Unit	Condition
Pulse width	t _w	3.3	—	5.0	7.0	ns	Cext = 0 pF
\overline{A} or B or \overline{C}_{Dn}		5.0	—	4.5	5.0		Rext = 5 kΩ
Recovery time	t _{rec}	3.3		2.0	2.0	ns	
\overline{C}_{Dn} to \overline{A} or B		5.0	_	2.0	2.0		

 Note:
 1.
 Voltage Range 3.3 is 3.3 V ± 0.3 V

 Voltage Range 5.0 is 5.0 V ± 0.5 V

			Ta = +25°C C _∟ = 50 pF			Ta = -40°C to +85°C C _∟ = 50 pF			
Item	Symbol	V _{cc} (V)* ¹	Min	Тур	Max	Min	Max	Unit	Condition
Output pulse width	T _{WQ}	3.3	—	_	—	—	_	ms	Cext = 0.1 µF
		5.0	0.90	_	1.10	0.85	1.15		Rext = 10 kΩ
Minimum output	T _{WQ(min)}	3.3	190	_	350	170	380	ns	Cext = 28 pF
pulse width		5.0	160	_	300	140	330		R ext = 2 k

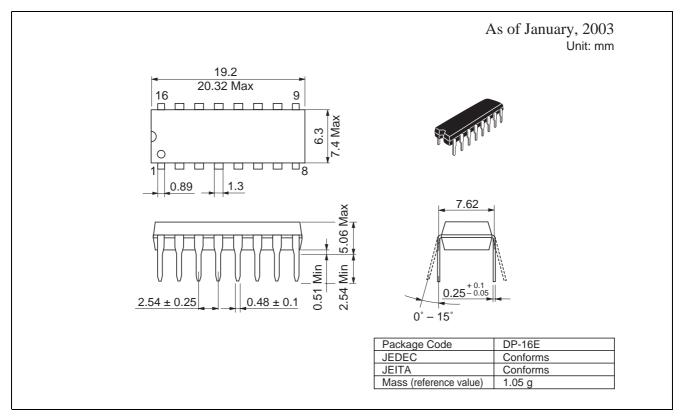
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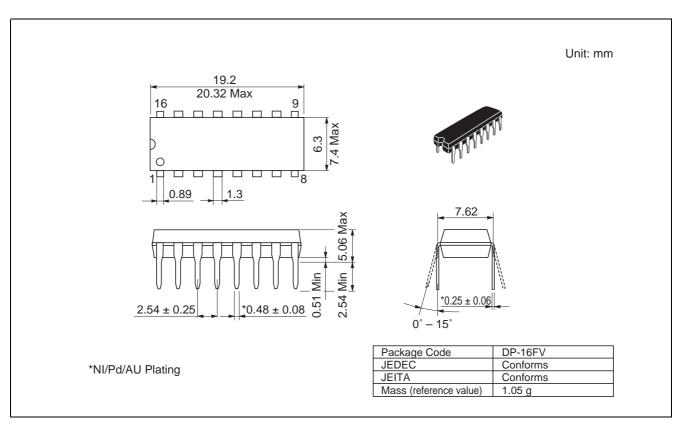
Voltage Range 5.0 is 5.0 V \pm 0.5 V

Cext and Rext should be connected as close to the IC terminals as possible, in order to prevent malfunction.

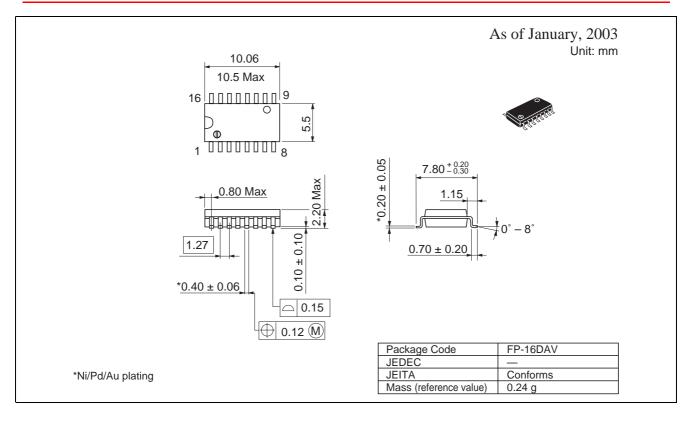


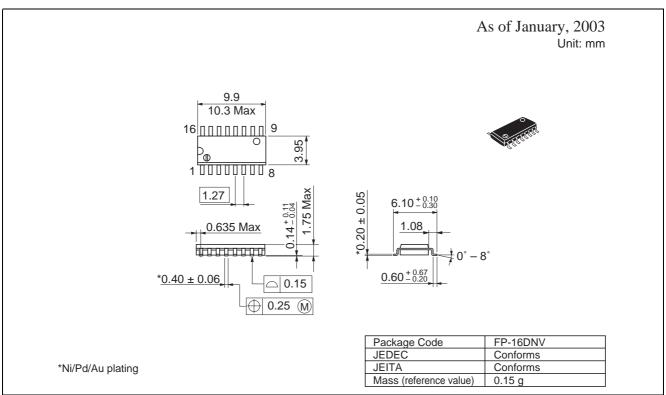
Package Dimensions











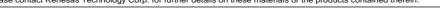


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